REFERENCE VOLTAGE GENERATOR WITH SUPPLY VOLTAGE AND TEMPERATURE IMMUNITY

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates generally to reference voltage generators, and more particularly, to reference voltage generators with supply voltage and temperature immunity.

2. Description of Related Art

Reference voltage generators have traditionally been temperature dependent. As temperature changes, a reference voltage produced by the reference voltage generator has traditionally changed accordingly. A need thus exists in the prior art to provide a reference voltage that is substantially unchanged as temperature changes.

SUMMARY OF THE INVENTION

The present invention addresses the above-stated need by providing a reference voltage generator that provides a reference voltage at a reference voltage node. The reference voltage can be substantially invariant with respect to temperature. A reference voltage with supply voltage and temperature immunity is generated by applying the gate-source voltage difference of a PMOS transistor across a first resistive element to generate a current and mirroring the current on a second resistive element connected with an NMOS transistor in parallel to compensate for the variations in the current of the PMOS transistor.

Any feature or combination of features described herein are included within the scope of the present invention provided that the features included in any such combination are not mutually inconsistent as will be apparent from the context, this specification, and the knowledge of one skilled in the art. For purposes of summarizing the present invention, certain aspects, advantages and novel features of the present invention have been described herein. Of course, it is to be understood that not necessarily all such aspects, advantages or features will be embodied in any particular embodiment of the present invention. Additional advantages and aspects of the present invention are apparent in the following detailed description and claims.

BRIEF DESCIRPTION OF THE DRAWINGS

FIG. 1 is a schematic diagram of a first circuit in accordance with an illustrated embodiment of the present invention;

FIG. 2 is a schematic diagram of a second circuit in accordance with another illustrated embodiment of the present invention;

FIG. 3 is a simulation depicting a potential of node C as a function of time in accordance with an illustrated embodiment of the present invention; and

FIG. 4 is a collection of graphs showing various voltages as a function of time in accordance with an illustrated embodiment of the present invention.

DETAILED DESCRIPTION OF THE PRESENTLY PREFERRED EMBODIMENTS

Reference will now be made in detail to the presently preferred embodiments of the invention, examples of which are illustrated in the accompanying drawings. Wherever possible, the same or similar reference numbers are used in the drawings and the description to refer to the same or like parts. It should be noted that the drawings are in simplified form and are not to precise scale. In reference to the disclosure herein, for purposes of convenience and clarity only, directional terms, such as, top, bottom, left, right, up, down, over, above, below, beneath, rear, and front, are used with respect to the accompanying drawings. Such directional terms should not be construed to limit the scope of the invention in any manner.

Although the disclosure herein refers to certain illustrated embodiments, it is to be understood that these embodiments are presented by way of example and not by way of limitation. The intent of the following detailed description, although discussing exemplary embodiments, is to be construed to cover all modifications, alternatives, and equivalents of the embodiments as may fall within the spirit and scope of the invention as defined by the appended claims. It is to be understood and appreciated that the process steps and structures described herein do not cover a complete process flow for the manufacture of a reference voltage generator. The present invention may be practiced in conjunction with various circuits that require a reference voltage, including several techniques that are conventionally used in the art, and only so much of the commonly practiced process steps are included herein as are necessary to provide an understanding of the present invention. The present invention has applicability in the field of supply voltages and temperature immunity in general. For illustrative purposes,

however, the following description pertains to a reference voltage generator with supply voltage and temperature immunity.

Referring now to FIG. 1, a first circuit in accordance with an illustrated embodiment of the present invention is shown, comprising a first current path I_A including a current source transistor M_1 and a feedback transistor M_4; a compensation current path I_B including a first resistor R_1, a feedback control transistor M_3, and a feedback-generating transistor M_5; and a second current path I_C including an output transistor M_2, a thermal coupling transistor M_6, a second resistor R_2, and an output capacitor C_1.

Referring now to the first current path I_A, the current source transistor M_1 is a PMOS transistor having a source terminal coupled to a supply signal VDD, a drain terminal coupled to a feedback control node A, and a gate terminal coupled to a central node B. The feedback transistor M_4 is an NMOS transistor having a drain terminal coupled to the feedback control node A, a source terminal coupled to a ground node, and a gate terminal coupled to a current mirror node C.

Referring now to the compensation current path I_B, the first resistor R_1 is coupled between the supply signal V_{DD} and the central node B. The feedback control transistor M_3 is a PMOS transistor having a source terminal coupled to the central node B, a drain terminal coupled to the current mirror node C, and a gate terminal coupled to the feedback control node A. The feedback-generating transistor M_5 is an NMOS transistor having a source terminal coupled to the ground node, a drain terminal coupled to the current mirror node C, and a gate terminal also coupled to the current mirror node C.

Referring now to the second current path I_C, the output transistor M_2 is a PMOS transistor having a source terminal coupled to the supply signal V_{DD}, a drain terminal coupled to an output node V_{REF}, and a gate terminal coupled to the central node B. The thermal coupling transistor M_6 is an NMOS transistor having a source terminal coupled to the ground node, and both a drain terminal and a gate terminal coupled to the output node V_{REF}. The second resistor R_2 and the output capacitor C_1 are coupled between the output node V_{REF} and the ground node, such that the second resistor R_2 and the output capacitor C_1 are in parallel with the gate-source and drain-source voltages of the thermal coupling transistor M_6.

Power-up

When power is initially applied to the circuit and the supply signal V_{DD} begins to ramp up to its operational voltage, the voltage at the central node B follows the voltage of the supply signal V_{DD} across the first resistor R1. Current begins to flow through the compensation current path I_B to the central node B, capacitively increasing the voltage of the central node B. Similarly, when power is initially applied to the circuit and the supply signal V_{DD} begins to ramp up to its operational voltage, the voltage at the feedback control node A has a voltage approximately equal to ground voltage. As voltage of the central node B increases while the voltage at the feedback control node A remains approximately zero, current flows through the feedback control transistor M_3 to the current mirror node C, capacitively increasing the voltage of the current mirror node C. As the voltage of the current mirror node C increases, current begins to flow through the feedback-generating transistor M_5.

When a current path through the feedback control transistor M_3 and the feedback-generating transistor M_5 begins to form between the central node B and ground through the compensation current path I_B, any residual capacitive charge at the central node B is discharged. As the voltage at the central node B is reduced, a quiescent current begins to flow through the first resistor R1, creating a voltage difference between the supply signal V_{DD} and the central node B.

The first current path I_A and the compensation current path I_B

Within the first current path I_A, the voltage difference between the supply signal V_{DD} and the central node B imposes a gate-to-source voltage V_{GS1} on the current source transistor M_1. The gate-to-source voltage V_{GS1} causes a current to flow through the current source transistor M_1 and through the first current path I_A. Current through the first current path I_A passes through the current source transistor M_1 and through the feedback transistor M_4 to ground.

Within the compensation current path I_B, the voltage difference between the supply signal V_{DD} and the central node B further creates a current in the compensation current path I_B through the first resistor R_1. In accordance with Ohm's law, the current in the compensation current path I_B is $I_B = V_{GS1}/R_1$. The current passes through the first resistor R_1 and through both the feedback control transistor M_3 and through the feedback-generating transistor M_5 to ground.

The reference voltage generator therefore has a first current source, i.e., the current source transistor M_1, that generates the first current I_A. The current source transistor M_1 has a first

temperature coefficient, which is generally positive since the current source transistor M_1 is a PMOS transistor. With changes in temperature, the current source transistor M_1 can apply a gate-source voltage difference on the first resistive element (i.e., the first resistor R_1), generate a first current through the current source transistor M_1, and conduct a compensation current through the first resistor R1.

The compensation current varies in response to the first current, such that a one-to-one correspondence exists between the compensation current and the first current. In other words, for any given first current through the current source transistor M_1, only one compensation current through the first resistor R_1 is possible. Moreover, as the first current through the current source transistor M_1 increases, the compensation current through the first resistor R_1 also increases; and as the first current through the current source transistor M_1 decreases, the compensation current through the first resistor R_1 also decreases.

Advantageously, the feedback-generating transistor M_5 and the feedback transistor M_4 form a feedback current mirror that stabilizes the current through the first current path I_A and the current through the compensation current path I_B. If the current through the compensation current path I_B increases, for example, then the gate-to-source voltage of the feedback-generating transistor M_5 increases accordingly, increasing the gate-to-source voltage of the feedback transistor M_4 across the feedback current mirror formed by the feedback-generating transistor M_5 and the feedback transistor M_4. The consequently greater voltage at the feedback control node A restricts the current through the feedback control transistor M_3, curtailing the current through the compensation current path I_B.

Similarly, if the current through the compensation current path I_B decreases, then the gate-to-source voltage of the feedback-generating transistor M_5 decreases accordingly, decreasing the gate-to-source voltage of the feedback transistor M_4 across the feedback current mirror formed by the feedback-generating transistor M_5 and the feedback transistor M_4. The consequently lower voltage at the feedback control node A allows more current to flow through the feedback control transistor M_3, increasing the current through the compensation current path I_B.

The feedback control transistor M_3 is a feedback element that conducts the compensation current such that the compensation current varies *inversely* in response to the first current. In other words, as the first current increases, raising the voltage of the feedback control node A, the

compensation current decreases, and as the first current decreases, lowering the voltage of the feedback control node A, the compensation current increases. The feedback element and the first resistor R_1 (i.e., a compensation element) operate to restore the first current to a substantially constant first current.

Thus, there are two independent relationships between the first current path I_A and the compensation current path I_B. First, the voltage across the gate and source terminals of the current source transistor M_1 (i.e., the voltage difference between the supply signal V_{DD} and the central node B) is equal to the voltage across the first resistor R_1. Second, the current through the feedback-generating transistor M_5 is related to the feedback transistor M_4 across the feedback current mirror. The two independent relationships provide a restorative feedback that inhibits fluctuations in the current through the first current path I_A (and the current through the compensation current path I_B). Since the gate and drain terminals of M5 are connected together, the Vgs of M5 equals the Vds (i.e., the voltage difference between the drain terminal and the gate terminal) of M5. The Vds of the transistor M5 is greater than Vgs-Vt. Therefore M5 will operate within the saturation region. Since M5 operates within the saturation region, Ids=k(W/L)(Vgs-Vt)(Vgs-Vt). In other words, if the dimensions of M4 and M5 are equal, then the current through M4 will be equal to that of M5.

The first current path I_A and the second current path I_C

The voltage difference V_{GS1} of the current source transistor M_1 is further mirrored on the output transistor M_2 to produce a current through the second current path I_C. In other words, the current source transistor M_1 and the output transistor M_2 form an output current mirror that produces a current through the second current path I_C.

A current divider serves to stabilize the voltage at the output node V_{REF} by stabilizing the current through the thermal coupling transistor M_6 and through the second resistor R_2. The second resistor R_2 is an output device that is operative to provide a reference voltage in response to the second current. The current through the second current path I_C is divided between the thermal coupling transistor M_6 and the second resistor R_2. The voltage at the output node V_{REF} is applied as a gate-to-source voltage of the thermal coupling transistor M_6, causing a current I_{M6} to flow through the thermal coupling transistor M_6. The voltage at the output node V_{REF} is also applied across the second resistor R_2, corresponding to flow of a current I_{R2} through the second

resistor R_2.

When the output capacitor C_1 draws no current, the current I_{M6} through the thermal coupling transistor M_6 and the current I_{R2} through the second resistor R_2 may be added together to total the current through the second current path I_C. If the voltage at the output node V_{REF} increases, the resulting increase in gate-to-source voltage across the thermal coupling transistor M_6 draws more current through the thermal coupling transistor M_6, attenuating the current through the second resistor R_2 and thereby restoring voltage at the output node V_{REF}.

Similarly, if the voltage at the output node V_{REF} decreases, the resulting decrease in gate-to-source voltage across the thermal coupling transistor M_6 restricts current through the thermal coupling transistor M_6 and diverts more of the current through the second current path I_C toward the second resistor R_2, thereby restoring the voltage at the output node V_{REF}. Since the current-to-voltage relationship of the thermal coupling transistor M_6 is independent of the current-to-voltage relationship of the second resistor R_2, while the voltages (the voltage at the output node V_{REF}) are identical and the current must total the current through the second current path I_C, the two independent current-to-voltage relationships provide a restorative feedback that maintains the voltage at the output node V_{REF} substantially constant.

The temperature dependence of the current source transistor M_1 is removed by compensation with the thermal coupling transistor M_6, in combination with the first resistor R_1 and the second resistor R_2. The current source transistor M_1 and the thermal coupling transistor M_6 have complementary thermal coefficients. The current source transistor M_1 is a PMOS transistor, and consequently may be expected to have a positive temperature coefficient. As temperature increases, current I_A through the current source transistor M_1 may be expected to increase. The increase in current is mirrored into the second current path I_C across the output current mirror formed by the current source transistor M_1 and the output transistor M_2, increasing the current through the parallel combination of the thermal coupling transistor M_6 and the second resistor R_2. Without temperature compensation, the output reference voltage would vary with V_{GS1}, in accordance with the relationship:

$V_{REF} = V_{GS1} * (R_2/R_1)$, or

$\partial V_{REF} / \partial T = (R_2/R_1) (\partial V_{GS1} / \partial T) > 0$, where T = temperature.

The thermal coupling transistor-like element M6 provides the necessary thermal compensation to maintain the output reference voltage regardless of thermal variations in VGS1. The thermal coupling transistor-like element M6 is a PMOS transistor, and consequently may be expected to have a positive temperature coefficient. As temperature increases, current through the thermal coupling transistor-like element M6 may be expected to increase, shunting a greater current from the second resistor R2 and allowing the voltage across the second resistor R2 to remain constant despite a greater current through the first resistor R1. Similarly, as temperature decreases, current through the thermal coupling transistor-like element M6 may be expected to decrease, diverting a greater portion of the first current from the first resistor R1 into the second resistor R2 and (again) allowing the voltage across the second resistor R2 to remain constant despite a greater current through the first resistor R1. However, the increased current flow through the second resistor R_2 will increase the voltage across the second resistor R_2, thereby increasing current flow through the thermal coupling transistor M_6 and offsetting the temperature-induced decrease of current through the thermal coupling transistor M_6. The thermal coupling transistor M_6 is thus a shunt device that has a temperature coefficient which is complementary to the first temperature coefficient, being operatively coupled in parallel with the second resistor R2 and being operative to restore the reference voltage in response to temperature-dependent variations in the first current.

Threshold Voltage drops

An examination of various threshold voltage drops through the circuit provides additional insight into the operation of the circuit. Across either the current source transistor M_1 or the output transistor M_2, the voltage of the central node B is one PMOS threshold voltage drop below the voltage of the supply signal V_{DD}. Across either the current source transistor M_1 or the feedback control transistor M_3, the feedback control node A is one PMOS threshold voltage drop below the voltage of the central node B, and across the output transistor M_2 the output node V_{REF} is one PMOS threshold voltage drop below the voltage of the central node B. If the current source transistor M_1, the output transistor M_2, and the feedback control transistor M_3 are fabricated from a uniform doping concentration and are symmetric with respect to drain and source, then the voltage at the feedback control node A is equivalent to the voltage at the output node V_{REF}.

Across the feedback-generating transistor M_5, which is an NMOS transistor whose gate terminal is connected to its drain terminal and whose source terminal is connected to ground, the voltage of the current mirror node C is one NMOS threshold voltage drop above ground. FIG. 3 is simulation depicting a potential of node C as a function of time wherein a voltage of node C is about 1.2 volts. In the plot, D1:A0:v(c) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of -25C; D1:A1v(c) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of 25C; and D1:A3v(c) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of 85C.

Across the thermal coupling transistor M_6, which is an NMOS transistor whose gate terminal is connected to its drain terminal and whose source terminal is connected to ground, the voltage of the output reference node V_{REF} can be interpreted to be two NMOS threshold voltage drops above ground. Thus, a sequence of threshold voltage drops from the supply signal V_{DD} to ground includes two NMOS threshold voltage drops and two PMOS threshold voltage drops. Any positive temperature coefficient of the PMOS transistors can be compensated by a corresponding negative temperature coefficient of the NMOS transistors, resulting in a substantially temperature-independent total voltage drop between the supply signal V_{DD} and ground. As mentioned, the voltage of node V_{REF} is equal to I_{R2}*R2. In the illustrated embodiment wherein the value of R2 is fixed, if I_{R2} is also fixed, then the voltage of node V_{REF} is stable. In accordance with current mirror principles, I_A is equal to I_C. I_C in turn is equal to $I_{R2}+I_{M6}$. When the components of M1 and M6 are set to have the same or about the same temperature coefficients (e.g., all positive or all negative), then when I_A increases I_{M6} increases also, and vice versa. This behavior can facilitate a stabilization of I_{R2} and V_{REF}.

Referring now to FIG. 4, a collection of graphs shows various voltage waveforms as a function of time in accordance with the illustrated embodiment of the present invention, wherein v(out) in each plot denotes the potential of the output reference node V_{REF}. In the first panel of FIG. 4, D0:A0:v(out) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of -25C, yielding a relatively slow corner characteristic; D0:A1:v(out) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of 25C, generating a relatively slow corner

characteristic; and D1:A2:v(out) corresponds to a scenario wherein VDD is 3.0 volts at a temperature of 85C, yielding a relatively slow corner characteristic. In the second panel, D0:A3:v(out) corresponds to a scenario wherein VDD is 3.3 volts at a temperature of -25C, generating a typical corner characteristic; D0:A4:v(out) corresponds to a scenario wherein VDD is 3.3 volts at a temperature of 25C, yielding a typical corner characteristic; and D0:A5:v(out) corresponds to a scenario wherein VDD is 3.3 volts at a temperature of 85C, generating a typical corner characteristic. In the third panel of FIG. 4, D1:A6:v(out) corresponds to a scenario wherein VDD is 3.7 volts at a temperature of -25C, yielding a relatively fast corner characteristic; D0:A7:v(out) corresponds to a scenario wherein VDD is 3.7 volts at a temperature of 25C, yielding a relatively fast corner characteristic; and D1:A8:v(out) corresponds to a scenario wherein VDD is 3.7 volts at a temperature of 85C, generating a relatively fast corner characteristic.

Output capacitor C1

With further reference to FIG. 1, the output capacitor C_1 improves the stability of the output node V_{REF}. The output capacitor C_1 and the second resistor R_2 form an RC circuit that serves to stabilize the output reference voltage at the output node V_{REF} by slowing variations in the output node V_{REF}.

The second circuit

Turning now to FIG. 2, a second circuit in accordance with the illustrated embodiment of the present invention is shown. The second circuit comprises: a first current path I_A including a current source transistor-like element M_1 and a feedback transistor-like element M_4; a compensation current path I_B including a first resistive-like element R_1, a feedback control transistor-like element M_3, and a feedback-generating transistor-like element M_5; and a second current path I_C including an output transistor-like element M_2, a thermal coupling transistor-like element M_6, a second resistive-like element R_2, and an output capacitor-like element C_1.

Referring now to the first current path I_A, the current source transistor-like element M_1 can

be, for example, a PMOS transistor having a source terminal coupled to a supply signal V_{DD}, a drain terminal coupled to a feedback control node A, and a gate terminal coupled to the central node B. The feedback transistor-like element M_4 can be, for example, an NMOS transistor having a drain terminal coupled to the feedback control node A, a source terminal coupled to a ground node, and a gate terminal coupled to a current mirror node C.

Referring now to the compensation current path I_B, the first resistive-like element R_1 is coupled between the supply signal V_{DD} and the central node B. The feedback control transistor-like element M_3 can be, for example, a PMOS transistor having a source terminal coupled to the central node B, a drain terminal coupled to the current mirror node C, and a gate terminal coupled to the feedback control node A. The feedback-generating transistor-like element M_5 can be, for example, an NMOS transistor having a source terminal coupled to the ground node, a drain terminal coupled to the current mirror node C, and a gate terminal also coupled to the current mirror node C.

Referring now to the second current path I_C, the output transistor-like element M_2 can be, for example, a PMOS transistor having a source terminal coupled to the supply signal V_{DD}, a drain terminal coupled to the output node V_{REF}, and a gate terminal coupled to the central node B. The thermal coupling transistor-like element M_6 can be, for example an NMOS transistor having a source terminal coupled to the ground node, and both a drain terminal and a gate terminal coupled to the output node V_{REF}. The second resistive-like element R_2 and the output capacitor-like element C_1 are coupled between the output node V_{REF} and the ground node, such that the second resistive-like element R_2 and the output capacitor-like element C_1 are in parallel with the gate-source and drain-source voltages of the thermal coupling transistor-like element M_6.

Power-up

When power is initially applied to the second circuit (i.e., the circuit of FIG. 2) and the supply signal V_{DD} begins to ramp up to its operational voltage, the voltage at the central node B follows the voltage of the supply signal V_{DD} across the first resistive-like element R1. Current begins to flow through the compensation current path I_B to the central node B, capacitively increasing the voltage of the central node B. Similarly, when power is initially applied to the second circuit and the supply signal V_{DD} begins to ramp up to its operational voltage, the voltage

at the feedback control node A has a voltage approximately equal to ground voltage. As voltage of the central node B increases while the voltage at the feedback control node A remains approximately zero, current flows through the feedback control transistor-like element M_3 into the current mirror node C, capacitively increasing the voltage of the current mirror node C. As the voltage of the current mirror node C increases, current begins to flow through the feedback-generating transistor-like element M_5.

When a current path through the feedback control transistor-like element M_3 and the feedback-generating transistor-like element M_5 begins to form between the central node B and ground through the compensation current path I_B, any residual capacitive charge at the central node B is discharged. As the voltage at the central node B is reduced, a quiescent current begins to flow through the first resistive-like element R1, creating a voltage difference between the supply signal V_{DD} and the central node B.

The first current path I_A and the compensation current path I_B

Within the first current path I_A, the voltage difference between the supply signal V_{DD} and the central node B imposes a gate-to-source voltage V_{GS1} on the current source transistor-like element M_1. The gate-to-source voltage V_{GS1} causes a current to flow through the current source transistor-like element M_1 and through the first current path I_A. Current through the first current path I_A passes through the current source transistor-like element M_1 and through the feedback transistor-like element M_4 to ground.

Within the compensation current path I_B, the voltage difference between the supply signal V_{DD} and the central node B also creates a current in the compensation current path I_B through the first resistive-like element R_1. In accordance with Ohm's law, the current in the compensation current path I_B is $I_B = V_{GS1}/R_1$. The current passes through the first resistive-like element R_1 and through both the feedback control transistor-like element M_3 and through the feedback-generating transistor-like element M_5 to ground.

Advantageously, the feedback-generating transistor-like element M_5 and the feedback transistor-like element M_4 form a feedback current mirror that stabilizes the current through the first current path I_A and the current through the compensation current path I_B. If the current through the compensation current path I_B increases, for example, then the gate-to-source voltage of the feedback-generating transistor-like element M_5 increases accordingly, increasing the

gate-to-source voltage of the feedback transistor-like element M_4 across the feedback current mirror formed by the feedback-generating transistor-like element M_5 and the feedback transistor-like element M_4. The consequently greater voltage at the feedback control node A restricts the current through the feedback control transistor-like element M_3, curtailing the current through the compensation current path I_B.

Similarly, if the current through the compensation current path I_B decreases, then the gate-to-source voltage of the feedback-generating transistor-like element M_5 decreases accordingly, decreasing the gate-to-source voltage of the feedback transistor-like element M_4 across the feedback current mirror formed by the feedback-generating transistor-like element M_5 and the feedback transistor-like element M_4. The consequently lower voltage at the feedback control node A allows more current to flow through the feedback control transistor-like element M_3, increasing the current through the compensation current path I_B.

Thus, there are two independent relationships between the first current path I_A and the compensation current path I_B. First, the voltage across the gate and source terminals of the current source transistor-like element M_1 (i.e., the voltage difference between the supply signal V_{DD} and the central node B) is equal to the voltage across the first resistive-like element R_1. Second, the current through the feedback-generating transistor-like element M_5 is related to the feedback transistor-like element M_4 across the feedback current mirror. The two independent relationships provide a restorative feedback that maintains the current through the first current path I_A (and the current through the compensation current path I_B) substantially constant.

The first current path I_A and the second current path I_C

The voltage difference V_{GS1} of the current source transistor-like element M_1 is further mirrored on the output transistor-like element M_2 to produce a current through the second current path I_C. In other words, the current source transistor-like element M_1 and the output transistor-like element M_2 form an output current mirror that produces a current through the second current path I_C.

A current divider serves to stabilize the voltage at the output node V_{REF} by stabilizing the current through the thermal coupling transistor-like element M_6 and through the second resistive-like element R_2. The current through the second current path I_C is divided between the thermal coupling transistor-like element M_6 and the second resistive-like element R_2. The

voltage at the output node V_{REF} is applied as a gate-to-source voltage of the thermal coupling transistor-like element M_6, causing a current I_{M6} to flow through the thermal coupling transistor-like element M_6. The voltage at the output node V_{REF} is also applied across the second resistive-like element R_2, causing a current I_{R2} to flow through the second resistive-like element R_2.

When the output capacitor-like element C_1 draws no current, the current I_{M6} through the thermal coupling transistor-like element M_6 and the current I_{R2} through the second resistive-like element R_2 may be added together to total the current through the second current path I_C. If the voltage at the output node V_{REF} increases, the resulting increase in gate-to-source voltage across the thermal coupling transistor-like element M_6 draws more current through the thermal coupling transistor-like element M_6, attenuating the current through the second resistive-like element R_2 and thereby restoring voltage at the output node V_{REF}.

Similarly, if the voltage at the output node V_{REF} decreases, the resulting decrease in gate-to-source voltage across the thermal coupling transistor-like element M_6 restricts current through the thermal coupling transistor-like element M_6 and diverts more of the current through the second current path I_C toward the second resistive-like element R_2, thereby restoring the voltage at the output node V_{REF}. Since the current-to-voltage relationship of the thermal coupling transistor-like element M_6 is independent of the current-to-voltage relationship of the second resistive-like element R_2, while the voltages (the voltage at the output node V_{REF}) are identical and the current must total the current through the second current path I_C, the two independent current-to-voltage relationships provide a restorative feedback that maintains the voltage at the output node V_{REF} substantially constant.

The temperature dependence of the current source resistive-like element M_1 is removed by compensation with the thermal coupling transistor-like element M_6, in combination with the first resistive-like element R_1 and the second resistive-like element R_2. The current source transistor-like element M_1 and the thermal coupling transistor-like element M_6 have complementary thermal coefficients. The current source transistor-like element M_1 is a PMOS transistor, and consequently may be expected to have a positive temperature coefficient. As temperature increases, current in the first current path I_A through the current source transistor-like element M_1 may be expected to increase. The increase in current is mirrored into the second current path I_C across the output current mirror formed by the current source

transistor-like element M_1 and the output transistor-like element M_2, increasing the current through the parallel combination of the thermal coupling transistor-like element M_6 and second resistive-like element R_2. Without temperature compensation, the output reference voltage would vary with V_{GS1}, in accordance with the relationship:

$V_{REF} = V_{GS1}*(R_2/R_1)$, or

$\partial V_{REF} / \partial T = (R_2/R_1)(\partial V_{GS1} / \partial T) > 0$, where T = temperature.

The thermal coupling transistor-like element M_6 provides the necessary thermal compensation to maintain the output reference voltage regardless of thermal variations in V_{GS1}. The thermal coupling transistor-like element M_6 is an NMOS transistor, and consequently may be expected to have a negative temperature coefficient. As temperature increases, current through the thermal coupling transistor-like element M_6 may be expected to decrease, and consequently greater current is directed through the second transistor R_2. Since the increase in temperature has restricted the ability of the thermal coupling transistor-like element M_6 to conduct current, even more of the current passes through the second resistive-like element R_2. However, as mentioned above in connection with the FIG. 1 circuit, the increased current flow through the second resistive-like element R_2 will increase the voltage across the second resistive-like element R_2, thereby increasing current flow through the thermal coupling transistor-like element M_6 and offsetting the temperature-induced decrease of current through the thermal coupling transistor-like element M_6.

Output capacitor-like element C1

Further, output capacitor-like element C_1 improves the stability of the output node V_{REF}. The output capacitor-like element C_1 and the second resistive-like element R_2 form an RC circuit that serves to stabilize the output reference voltage at the output node V_{REF} by slowing variations in the output node V_{REF}.

In view of the foregoing, it will be understood by those skilled in the art that the methods of the present invention can provide a reference voltage with substantial temperature immunity in response to a supply voltage. The above-described embodiments have been provided by way of

example, and the present invention is not limited to these examples. Multiple variations and modifications to the disclosed embodiments will occur, to the extent not mutually exclusive, to those skilled in the art upon consideration of the foregoing description. For example, various resistive-like element combinations can replace the first and second resistive-like elements. Moreover, various combinations of the current source transistor-like element and the thermal coupling transistor-like element with opposite temperature coefficients can be implemented. Additionally, other combinations, omissions, substitutions and modifications will be apparent to the skilled artisan in view of the disclosure herein. Accordingly, the present invention is not intended to be limited by the disclosed embodiments, but is to be defined by reference to the appended claims.